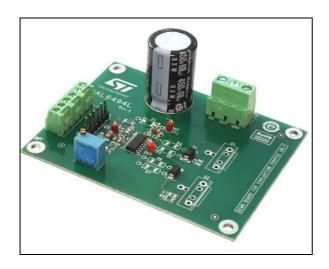




## Demonstration board for L6494L gate driver

**Data brief** 



#### **Features**

- Driver current capability: 2 A source, 2.5 A sink
- Integrated bootstrap diode
- Single input and shutdown pin
- · Adjustable deadtime
- 3.3 V, 5 V TTL/CMOS inputs with hysteresis
- UVLO on both high-side and low-side sections
- dV/dt immunity: 50 V/ns in full temperature range
- Compact and simplified layout
- · Bill of material reduction
- · Flexible, easy and fast design

### **Description**

The L6494L is a high voltage device manufactured with the BCD6 "OFF-LINE" technology. It is a single-chip half-bridge gate driver for N-channel power MOSFETs or IGBTs.

Both device outputs can sink 2.5 A and source 2 A, making the L6494L particularly suited for medium and high capacity power MOSFETs\IGBTs.

The integrated bootstrap diode as well as all of the integrated features of this driver make the application's PCB design simpler and more compact, and help reducing the overall bill of material.

The EVAL6494L board allows evaluating all of the L6494L features while driving a power switch in the TO-220 or TO-247 package.

The board allows easily to select and modify the values of relevant external components in order to ease driver performance evaluation under different applicative conditions and fine pre-tuning of final application components.

Schematic diagram EVAL6494L

## 1 Schematic diagram

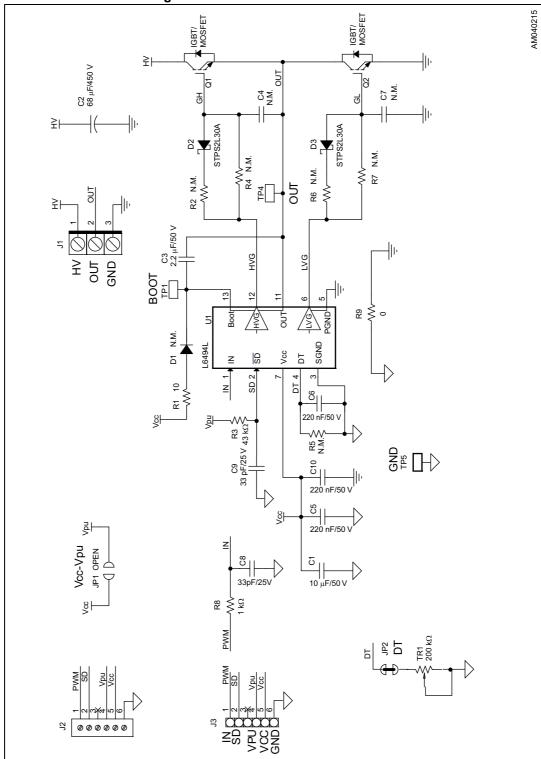


Figure 1. EVAL6494L circuit schematic

EVAL6494L Bill of material

## 2 Bill of material

Table 1. EVAL6494L - bill of material

Part reference	Part value	Part description	
C1	10 μF / 50 V	Ceramic capacitor, SMT 1206	
C2	68 μF / 450 V	Electrolytic capacitor, 68 µF, 450 V, 20% radial P7.5 mm 18 x 25	
C3	2.2 μF / 50 V	Ceramic capacitor, SMT 1206 or T.H.	
C4, C7	N. M.	Ceramic capacitor, SMT 0805	
C5, C10	220 nF / 50 V Ceramic capacitor, SMT 0805		
C6	220 nF / 50 V Ceramic capacitor, SMT 0603		
C8, C9	33 pF / 25 V Ceramic capacitor, SMT 0603		
D1	N. M.	Diode DO-41 or SMA	
D2, D3	STPS2L30A	Schottky diode 30 V, 2 A, SMA	
JP1	Jumper - OPEN SMT jumper		
JP2	Jumper - CLOSED SMT jumper		
J1	Phoenix Contact 1985991 or similar Conn. term. block. T.H. 3 POS 5.08 r		
J2	2 x Phoenix Contact 1984950 or similar Conn. term. block. T.H. 6 POS 3.5 r		
J3	FCI 68000-406HLF or similar Conn. header 6 POS 2.54 mm STR TIN		
Q1, Q2	To be selected by customer IGBT/MOSFET, TO-220 or TO-247		
R1	10 Ω Resistor, SMT 1206		
R2, R4, R6, R7	To be selected by customer Resistor, SMT 1206 or T.H.		
R3	43 kΩ Resistor, SMT 0603		
R5	N. M.	Resistor, SMT 0603	
R8	1 kΩ	Resistor, SMT 0603	
R9	0 Ω Resistor, SMT 0805		
TP1, TP4, TP5	RS 200-207 or similar PCB test terminal 1 mm		
TR1	Murata PV36W204C01B00 or similar	rata PV36W204C01B00 or similar Trimmer 200 kΩ, 0.5 W, T. H.	
U1	L6494LD High voltage high and low-side gate drive SO-14		

Layout EVAL6494L

# 3 Layout



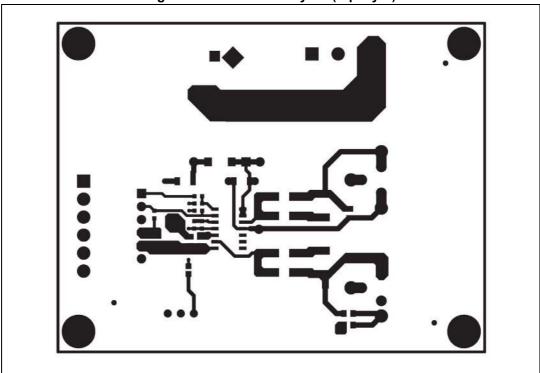
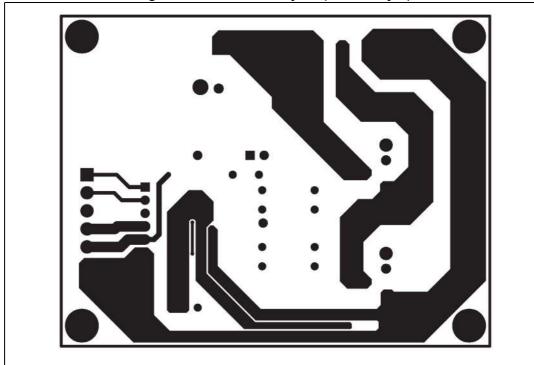


Figure 3. EVAL6494L - layout (bottom layer)



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EVAL6494L Layout

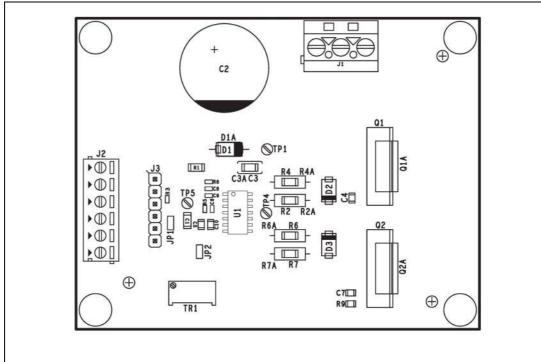


Figure 4. EVAL6494L - layout (component placement view)

Revision history EVAL6494L

# 4 Revision history

**Table 2. Document revision history** 

Date	Revision	Changes
14-Nov-2017	1	Initial release.

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